TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

# TA8218AH

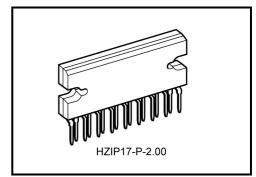
#### Audio Power Amplifier

The TA8218AH is 3 channel audio amplifier for consumer applications.

This IC provides an output power of 6 watts per channel (at  $V_{CC} = 20 \text{ V}$ , f = 1kHz, THD = 10%, RL = 8  $\Omega$ ). It is suitable for power amplifier of TV and home stereo.

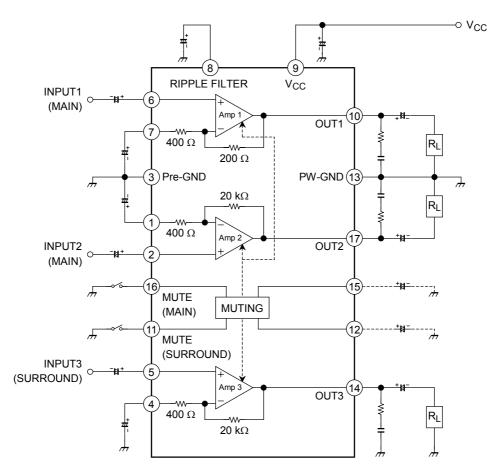
#### Features

- Built-in 3ch amplifier
- High output power: Pout = 6 W/ch (Typ.)  $(V_{CC} = 20 \text{ V}, \text{R}_{L} = 8 \ \Omega, \text{ f} = 1 \text{ kHz}, \text{THD} = 10\%)$
- Low noise: V<sub>no</sub> = 0.14 mVrms (Typ.) (V<sub>CC</sub> = 20 V, R<sub>L</sub> = 8 Ω, G<sub>V</sub> = 34dB, R<sub>g</sub> = 10 kΩ, BW = 20 Hz~20 kHz)
- Built in audio muting circuit (Active → Low)
  Main amp/surround amp independent control.
- Built in various protection circuits
  - Protection circuit: Thermal shut down, over voltage,  $\text{Out} \rightarrow \text{GND}$  short.
- Operation supply voltage range: V<sub>CC</sub> (opr) =  $10 \sim 30$  V (Ta =  $25^{\circ}$ C)



#### Weight: 9.8 g (typ.)

### **Block Diagram**



### Cautions

This IC is not proof enough against a strong E-M field by CRT which may cause malfunction such as leak. Please set the IC keeping the distance from CRT.

### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	30	V	
Output current (Peak/ch)	P <sub>D</sub> (Note)	50	W	
Operation temperature	T <sub>opr</sub>	-20~75	°C	
Storage temperature	T <sub>stg</sub>	-55~150	°C	

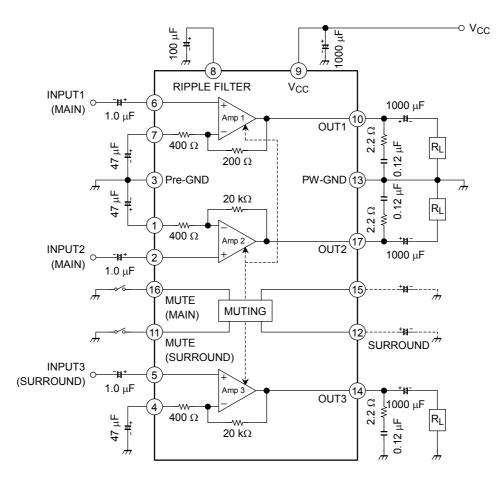
Note: Derated above  $Ta = 25^{\circ}C$  in the proportion of 400 mW/°C.

#### Electrical Characteristics (unless otherwise specified V<sub>CC</sub> = 20 V, R<sub>L</sub> = 8 $\Omega$ , R<sub>g</sub> = 600 $\Omega$ , f = 1 kHz, Ta = 25°C)

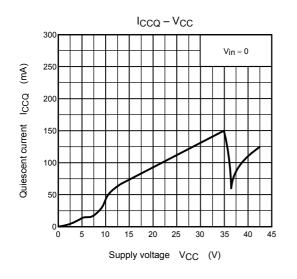
Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	
Quiescent current	ICCQ		$V_{in} = 0$	40	90	160	mA	
Output power	P <sub>out</sub> (1)		THD = 10%	5.0	6.0	—	W	
	P <sub>out</sub> (2)		THD = 1%		4.5	—	vv	
Total harmonic distortion	THD		$P_{out} = 2 W$	_	0.1	0.6	%	
Voltage gain	Gv		V <sub>out</sub> = 0.775 Vrms	32.5	34.0	35.5	dB	
Input resistance	R <sub>IN</sub>		—	_	30	_	kΩ	
Ripple rejection ratio	R.R.	_	Rg = 0, f <sub>ripple</sub> = 100 Hz, V <sub>ripple</sub> = 0.775 Vrms	-50	-60	_	dB	
Output noise voltage	V <sub>no</sub>	_	Rg = 10 kΩ, BW = 20 Hz~20 kHz	_	0.14	0.3	mVrms	
Cross talk	C.T.	_	Rg = 0, V <sub>out</sub> = 0.775 Vrms Two channels input		-60	_	dB	
Muting threshold voltage	V <sub>th (OFF)</sub>		Mute OFF 11/16 pin	_	3.7	4.0	v	
	V <sub>th (ON)</sub>		Mute ON 11/16 pin	2.5	2.8			
Muting attenuation	ATT		$V_{out} = 0.775 \text{ Vrms} \rightarrow \text{Mute}$ Three channels input	-52	-60		dB	

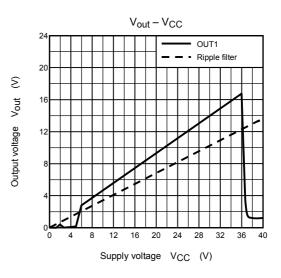
### <u>TOSHIBA</u>

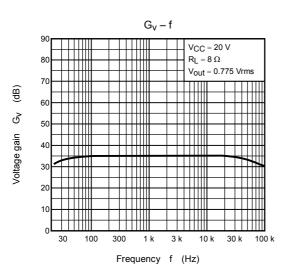
### **Test Circuit**

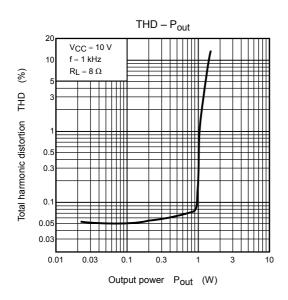


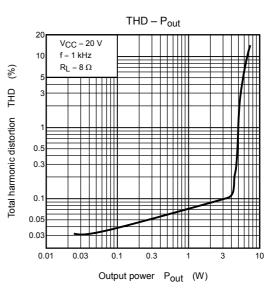
- \*1 16/11 pin LOW: mute ON Mute ON :  $V_{th}$  16/11 = 2.8 V (Typ.) ( $V_{CC}$  = 20 V, Ta = 25°C) Mute OFF:  $V_{th}$  16/11 = 3.7 V (Typ.) ( $V_{CC}$  = 20 V, Ta = 25°C)
- \*2 The capacitor for reducing POP noise at mute ON

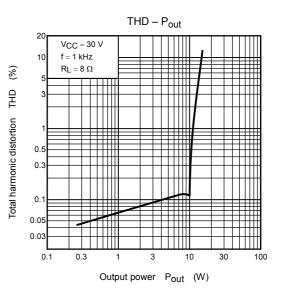


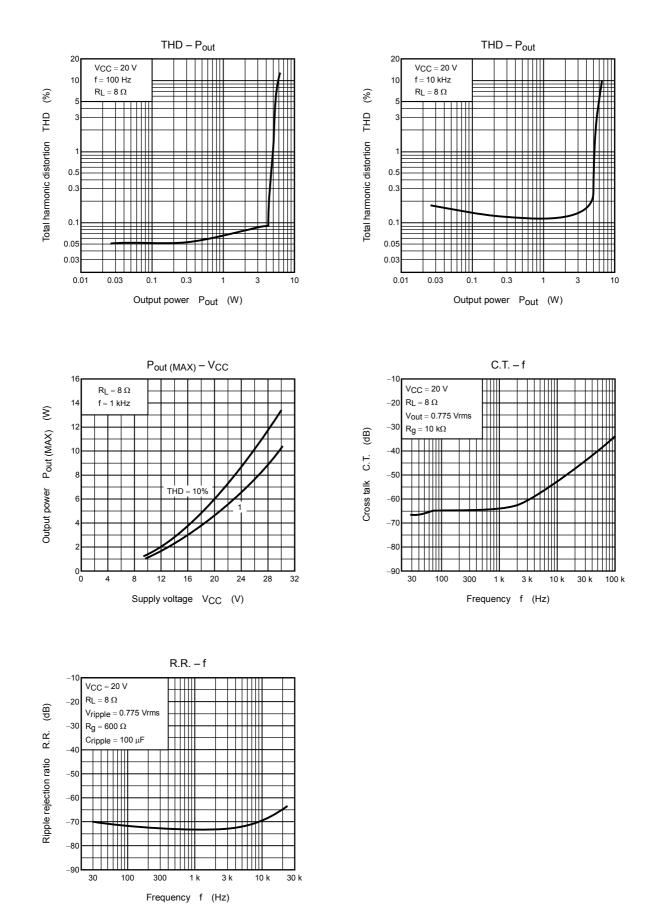


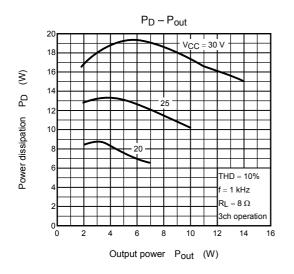


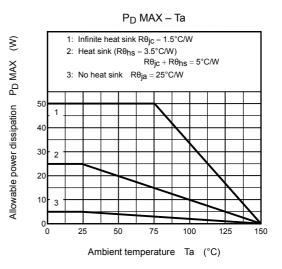








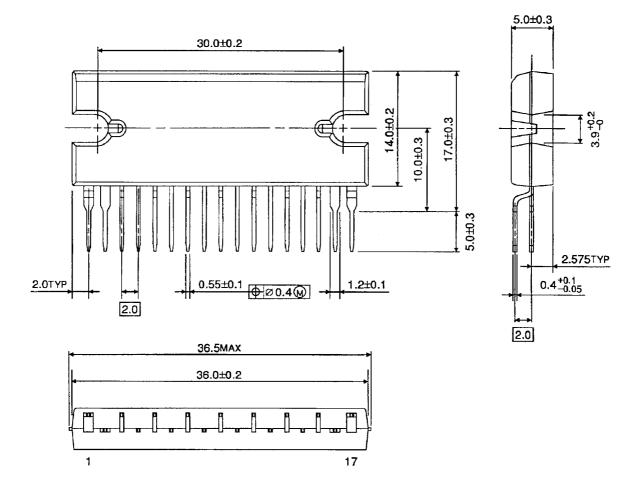




### Package Dimensions

HZIP17-P-2.00

Unit : mm



Weight: 9.8 g (typ.)

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